NSN 5961-01-452-8503

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Inclosure Material:
Metal
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0